

Features

- High Speed Smooth Switching Device for Hard and Soft Switching
- Maximum Junction Temperature 175°C
- Positive Temperature Coefficient
- High Ruggedness, Temperature Stable
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant (Note 2) ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Applications

- Soft Switching Applications
- Air Conditioning
- Motor Drive Inverter

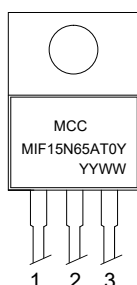
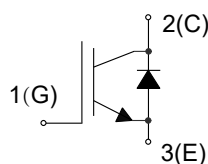
Maximum Ratings

Parameter	Symbol	Rating	Unit
Collector-Emitter Voltage	V_{CE}	650	V
DC Collector Current ⁽³⁾	I_C	20	A
		10	
Pulsed Collector Current, $V_{GE}=15V^{(4)}$	$I_{C,pluse}$	45	A
Diode Forward Current ⁽³⁾	I_F	20	A
		10	
Diode Pulsed Current ⁽⁴⁾	$I_{F,pluse}$	45	A
Continuous Gate-Emitter Voltage	V_{GE}	±20	V
Transient Gate-Emitter Voltage ⁽⁵⁾		±30	
Turn off Safe Operation Area, $V_{CE} \leq 600V, T_J \leq 150^\circ C$		45	A
Short Circuit Withstand Time ⁽⁶⁾	T_{SC}	5	μs
Power Dissipation, $T_C=25^\circ C, T_J=175^\circ C$	P_D	34	W

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. High Temperature Solder Exemptions Applied, see EU Directive Annex 7a.
3. Limited by T_{Jmax} .
4. t_p limited by T_{Jmax} .
5. $t_p \leq 10\mu s$, Duty Cycle < 1%
6. $V_{GE}=15V, V_{CE} \leq 400V$

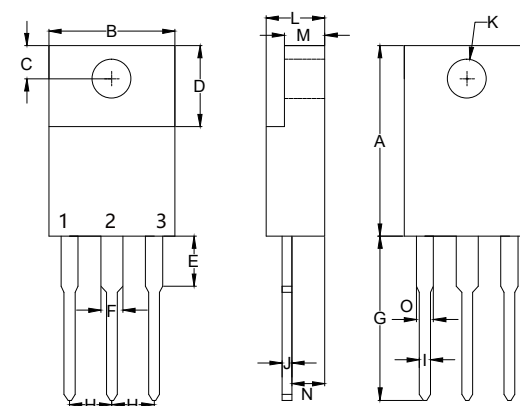
Internal Structure



Device Code: MIF15N65AT0Y
Date Code: YYWW (Year & Week)

Trench and Field Stop IGBT 650V 15A

ITO-220AB



DIMENSIONS					NOTE
DIM	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.567	0.642	14.40	16.30	
B	-----	0.421	-----	10.70	
C	0.085	0.128	2.15	3.25	
D	0.248	0.272	6.30	6.90	
E	-----	0.177	-----	4.50	
F	-----	0.071	-----	1.80	
G	0.500	0.539	12.70	14.20	
H	0.100		2.55		
I	-----	0.035	-----	0.90	
J	-----	0.032	-----	0.80	
K	0.102	0.150	2.60	3.80	Φ
L	-----	0.201	-----	5.10	
M	-----	0.140	-----	3.56	
N	0.083	0.126	2.10	3.20	
Q	-----	0.071	-----	1.80	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
IGBT Static Characteristics						
Collector-Emitter Breakdown Voltage	$V_{(BR)CES}$	$V_{GE}=0V, I_C=250\mu A$	650			V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V, I_C=15A, T_j=25^\circ C$		1.4	1.70	V
		$V_{GE}=15V, I_C=15A, T_j=125^\circ C$		1.55		
		$V_{GE}=15V, I_C=15A, T_j=150^\circ C$		1.6		
G-E Threshold Voltage	$V_{GE(th)}$	$I_C=1mA, V_{CE}=V_{GE}$	5.0	5.8	6.5	V
C-E Leakage Current	I_{CES}	$V_{CE}=650V, V_{GE}=0V, T_j=25^\circ C$			0.25	mA
		$V_{CE}=650V, V_{GE}=0V, T_j=150^\circ C$			1	
G-E Leakage Current	I_{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$			± 200	nA
Dynamic Characteristics						
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V, f=1MHz$		0.88		nF
Output Capacitance	C_{oes}			0.04		
Reverse Transfer Capacitance	C_{res}			0.01		
Gate Charge	Q_G	$V_{CC}=300V, I_C=15A, V_{GE}=15V$		0.069		μC
IGBT Switching Characteristics						
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=300V, I_C=15A,$ $V_{GE}=-5V\sim 15V,$ $R_G=51\Omega, T_j=25^\circ C$		10		ns
Rise Time	t_r			28		
Turn-Off Delay Time	$t_{d(off)}$			68		
Fall Time	t_f			138		
Turn-On Energy	E_{on}			0.33		mJ
Turn-Off Energy	E_{off}			0.16		
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=300V, I_C=15A$ $V_{GE}=-5V\sim 15V,$ $R_G=51\Omega, T_j=125^\circ C$		14		ns
Rise Time	t_r			36		
Turn-Off Delay Time	$t_{d(off)}$			69		
Fall Time	t_f			161		
Turn-On Energy	E_{on}			0.38		mJ
Turn-Off Energy	E_{off}			0.27		
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=300V, I_C=15A$ $V_{GE}=-5V\sim 15V,$ $R_G=51\Omega, T_j=150^\circ C$		16		ns
Rise Time	t_r			43		
Turn-Off Delay Time	$t_{d(off)}$			69		
Fall Time	t_f			182		
Turn-On Energy	E_{on}			0.43		mJ
Turn-Off Energy	E_{off}			0.32		
Short Circuit Collector Current	$I_{C(SC)}$	$V_{GE}=15V, t_{SC}\leq 5\mu s, V_{CC}=400V, T_{j,start}=25^\circ C$		110		A

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Diode Characteristics						
Diode Forward Voltage	V_F	$V_{GE}=0V, I_F=15A, T_j=25^{\circ}C$		1.9	2.4	V
		$V_{GE}=0V, I_F=15A, T_j=125^{\circ}C$		1.7		
		$V_{GE}=0V, I_F=15A, T_j=150^{\circ}C$		1.6		
Reverse Recovery Current	I_{rr}	$V_R=300V, I_F=15A,$ $di_F/dt=-380A/\mu s, T_j=25^{\circ}C$		6		A
Diode Reverse Recovery Time	t_{rr}			197		ns
Reverse Recovery Charge	Q_{rr}			0.24		μC
Reverse Recovery Energy	E_{rec}			0.06		mJ
Reverse Recovery Current	I_{rr}	$V_R=300V, I_F=15A,$ $di_F/dt=-380A/\mu s, T_j=125^{\circ}C$		7		A
Diode Reverse Recovery Time	t_{rr}			213		ns
Reverse Recovery Charge	Q_{rr}			0.58		μC
Reverse Recovery Energy	E_{rec}			0.11		mJ
Reverse Recovery Current	I_{rr}	$V_R=300V, I_F=15A,$ $di_F/dt=-380A/\mu s, T_j=150^{\circ}C$		8		A
Diode Reverse Recovery Time	t_{rr}			221		ns
Reverse Recovery Charge	Q_{rr}			0.71		μC
Reverse Recovery Energy	E_{rec}			0.14		mJ

Thermal characteristics

Parameter	Symbol	Min	Typ	Max	Units
Operating Junction Temperature Range	T_j	-40		175	$^{\circ}C$
Storage Temperature Range	T_{stg}	-55		150	$^{\circ}C$
Thermal Resistance from Junction to Case (IGBT)	$R_{th_{J-C}}$			4.4	$^{\circ}C/W$
Thermal Resistance from Junction to Case (Diode)	$R_{th_{J-C}}$			4.8	$^{\circ}C/W$
Thermal Resistance from Junction to Ambient	$R_{th_{J-A}}$			60	$^{\circ}C/W$

Curve Characteristics

Fig. 1 - Typical Output Characteristic($T_j=25^\circ\text{C}$)

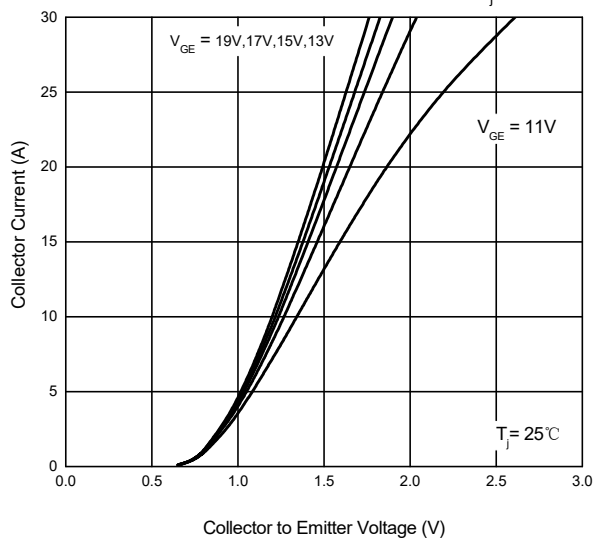


Fig. 2 - Typical Output Characteristic ($T_j=150^\circ\text{C}$)

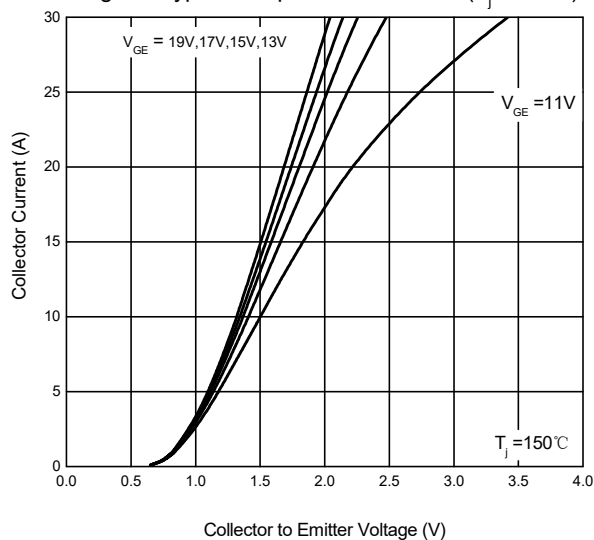


Fig. 3 - Typical Transfer Characteristic

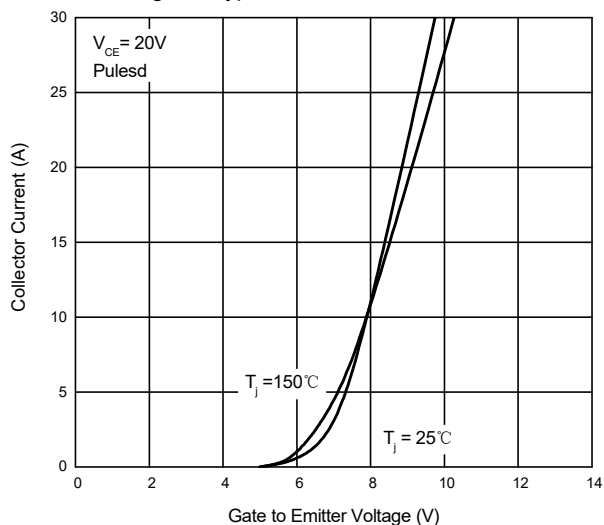


Fig. 4 - Diode Forward Current vs V_F

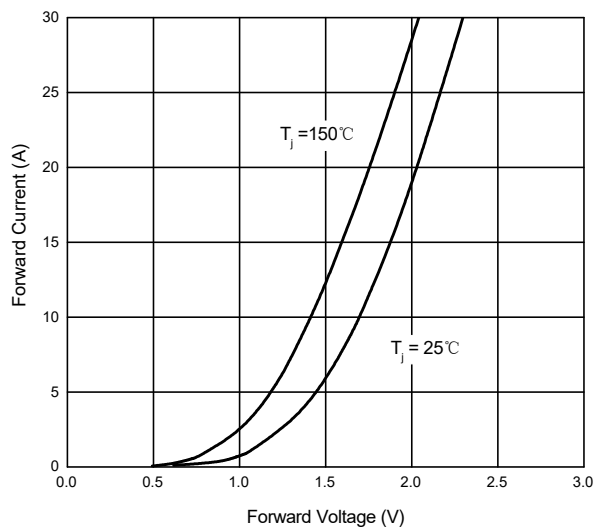


Fig. 5 - IGBT Switching Loss vs. I_C

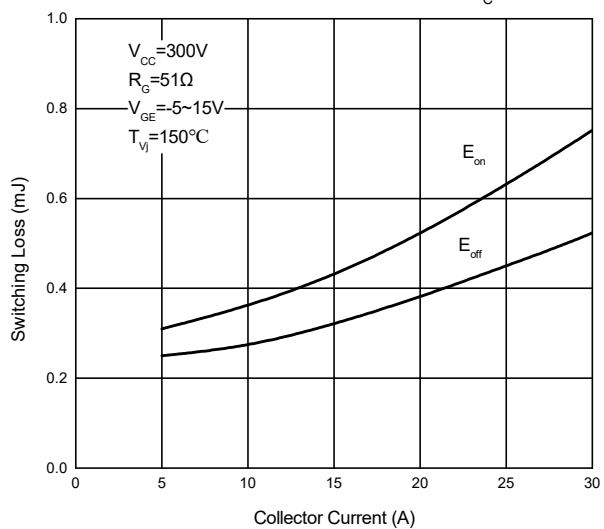
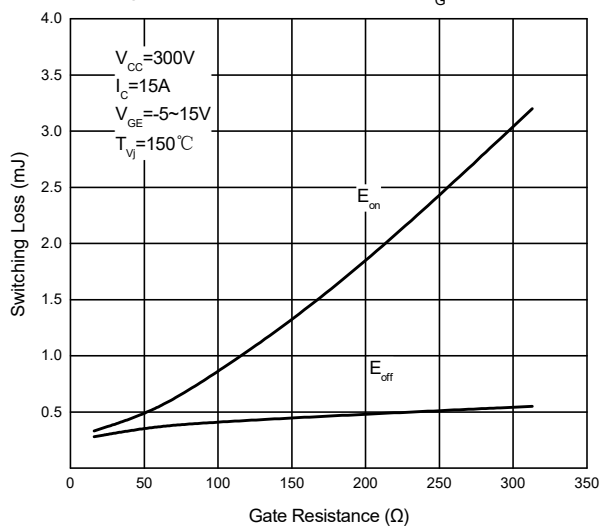


Fig. 6 - IGBT Switch Loss VS R_G



Curve Characteristics

Fig. 7 - Diode Switching Loss vs I_F

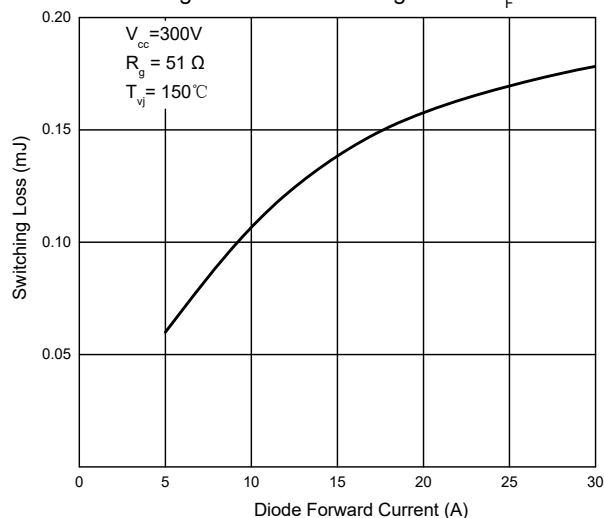


Fig. 8 - Diode Switching Loss vs R_G

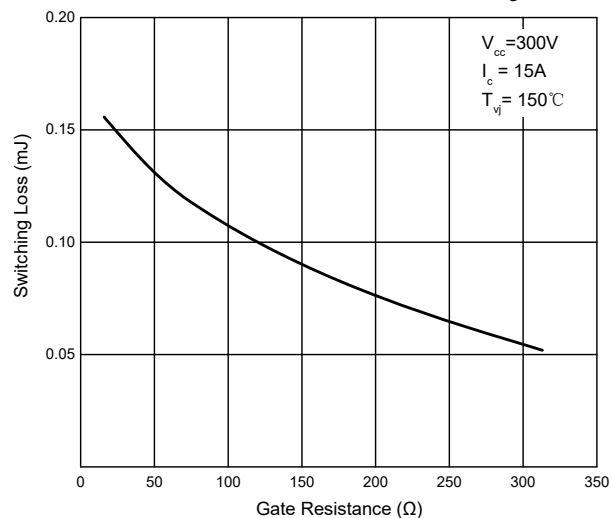


Fig. 9 - IGBT Transient Thermal Impedance

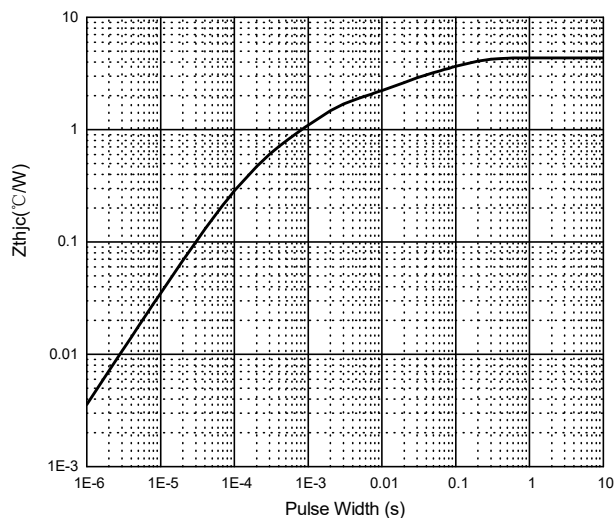


Fig. 10 - Diode Transient Thermal Impedance

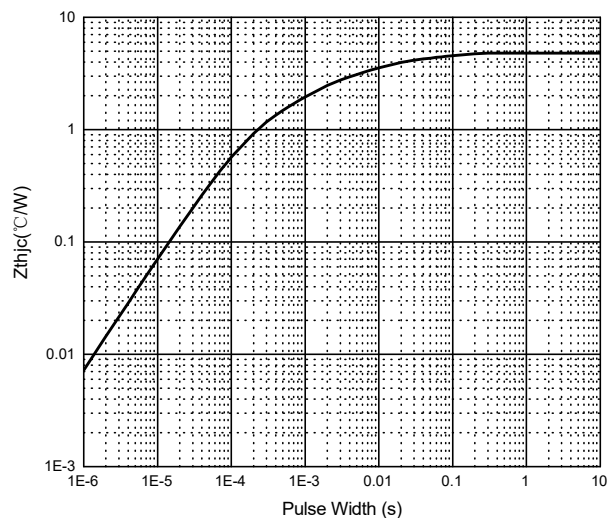


Fig. 11 - Collector Current vs Case Temperature

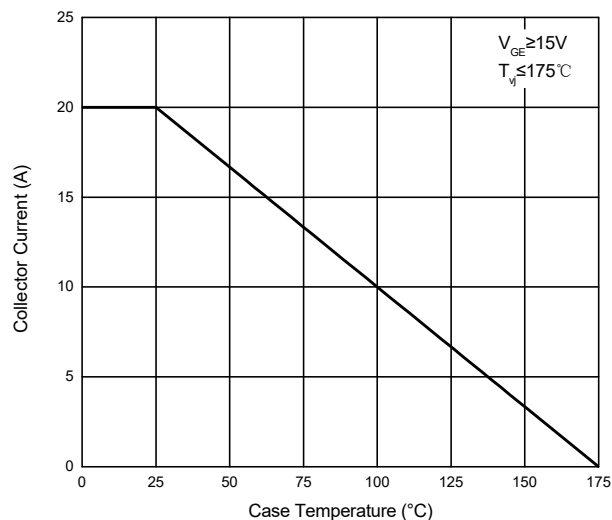
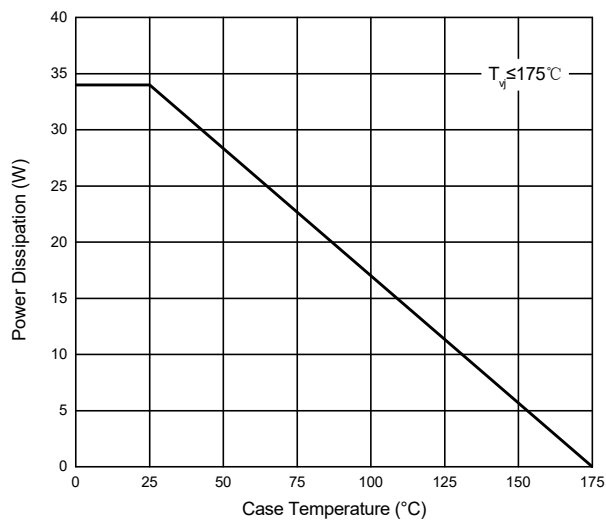


Fig. 12 - Power Derating



Ordering Information

Device	Packing
Part Number-BP	Bulk:50pcs/Tube, 1Kpcs/Box, 5Kpcs/Carton

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